RoHS

COMPLIANT

HALOGEN FREE

**GREEN** 



Vishay Semiconductors

# High Speed Infrared Emitting Diodes, 850 nm, Surface Emitter Technology



#### **DESCRIPTION**

As part of the <u>SurfLight<sup>TM</sup></u> portfolio, the VSMY5850 is an infrared, 850 nm emitting diode based on GaAlAs surface emitter chip technology with high radiant intensity, high optical power and high speed, in a low profile 0805 surface mount (SMD) package.

#### **FEATURES**

• Package type: surface-mount

• Package form: 0805

• Dimensions (L x W x H in mm): 2 x 1.25 x 0.8

Peak wavelength: λ<sub>p</sub> = 850 nm

· High speed

• Angle of half intensity:  $\varphi = \pm 60^{\circ}$ 

• 0805 standard surface-mountable package

 Floor life: 168 h, MSL 3, according to J-STD-020

• Lead (Pb)-free reflow soldering

 Material categorization: for definitions of compliance please see <a href="https://www.vishav.com/doc?99912">www.vishav.com/doc?99912</a>



- Miniature light barrier
- · Optical switch
- IR point source

PRODUCT SUMMARY				
COMPONENT	I <sub>e</sub> (mW/sr) at I <sub>F</sub> = 100 mA	φ (°)	$\lambda_{\mathbf{p}}$ (nm)	t <sub>r</sub> (ns)
VSMY5850	13	± 60	850	7

#### Note

· Test conditions see table "Basic Characteristics"

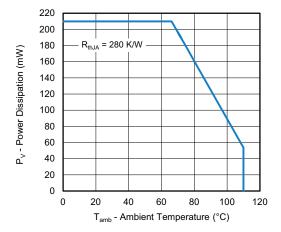
ORDERING INFORM	IATION		
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
VSMY5850	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	0805

#### Note

· MOQ: minimum order quantity



<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V <sub>R</sub>	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.1$ , $t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	500	mA	
Power dissipation		P <sub>V</sub>	210	mW	
Junction temperature		T <sub>j</sub>	125	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +110	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +110	°C	
Soldering temperature	According to Fig. 7, J-STD-020	T <sub>sd</sub>	260	°C	
Thermal resistance junction-to-ambient	EIA / JESD51	R <sub>thJA</sub>	280	K/W	





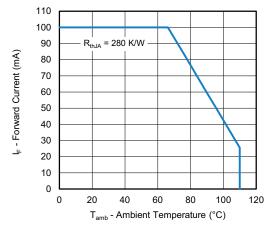


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$V_{F}$	-	1.8	2.1	V
Temperature coefficient of V <sub>F</sub>	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TK <sub>VF</sub>	-	-1.8	-	mV/K
Reverse current		I <sub>R</sub>	Not designed for reverse operation			μΑ
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,}$ $E = 0 \text{ mW/cm}^2$	CJ	-	30	-	pF
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	9	13	18	mW/sr
Temperature coefficient of radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	TΚφ <sub>e</sub>	-	-0.16	-	%/K
Angle of half intensity		φ	-	± 60	-	0
Peak wavelength	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$\lambda_{p}$	-	850	-	nm
Spectral bandwidth	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	Δλ	-	35	-	nm
Temperature coefficient of λ <sub>p</sub>	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	$TK_{\lambdap}$	-	0.25	-	nm/K
Rise time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>r</sub>	-	7	-	ns
Fall time	I <sub>F</sub> = 100 mA, 10 % to 90 %	t <sub>f</sub>	-	7	_	ns

#### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

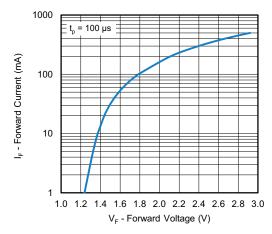
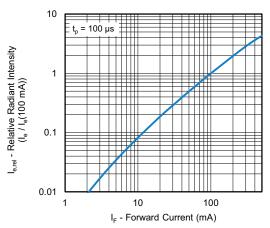


Fig. 3 - Forward Current vs. Forward Voltage



**REFLOW SOLDER PROFILE** 

Fig. 4 - Relative Radiant Intensity vs. Forward Current

#### 300 Max. 260 °C 255 250 240 200 remperature (°C) Max. 30 s 150 Max. 120 s Max. 100 s 100 Max. ramp down 6 °C/s 50 Max. ramp up 3 °C/s 0 50 100 200 250 300 150 19841 Time (s)

Fig. 7 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

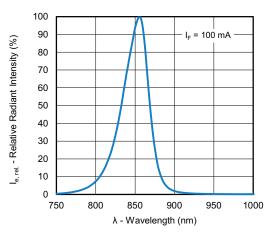


Fig. 5 - Relative Radiant Power vs. Wavelength

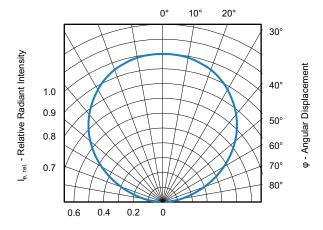


Fig. 6 - Relative Radiant Intensity vs. Angular Displacement

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 3

Floor life: 168 h

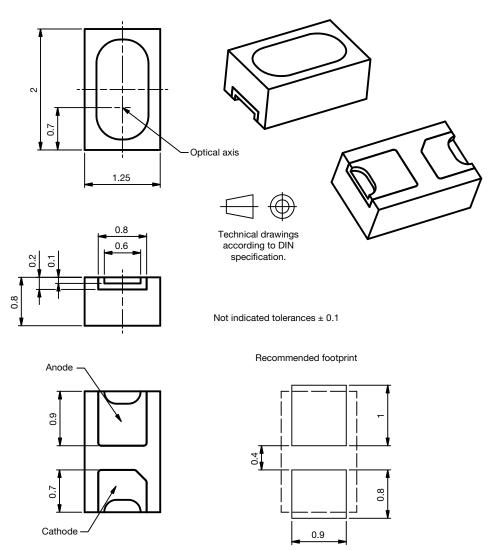
Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-033D or label. Devices taped on reel dry using recommended conditions 192 h at 40  $^{\circ}$ C (+ 5  $^{\circ}$ C), RH < 5  $^{\circ}$ M.



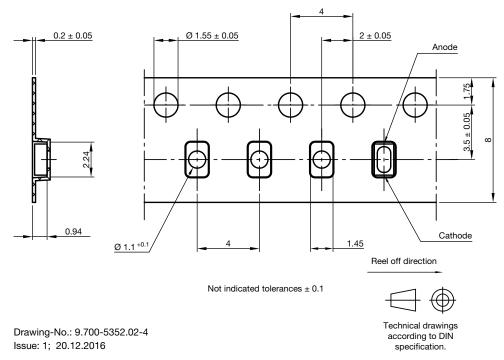
#### **PACKAGE DIMENSIONS** in millimeters

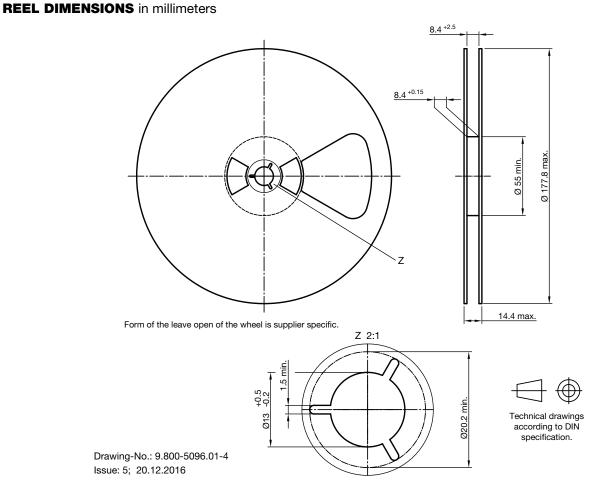


Drawing- No.: 6.550-5352.01-4

Issue: 1; 20.12.2016

#### **BLISTER TAPE DIMENSIONS** in millimeters







## **Legal Disclaimer Notice**

Vishay

## **Disclaimer**

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.